

SD101AW-V, SD101BW-V, SD101CW-V

Vishay Semiconductors

Small Signal Schottky Diodes

Features

- For general purpose applications
- The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications
- Pb-free (e3) RoHS

COMPLIANT

- The SD101 series is a Metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring
- These diodes are also available in the Mini-MELF case with type designations LL101A to LL101C, in the DO-35 case with type designations SD101A to SD101C and in the SOD-323 case with type designations SD101AWS-V to SD101CWS-V
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



Mechanical Data

Case: SOD-123 Weight: approx. 10.3 mg

Packaging Codes/Options:

GS18/10 k per 13" reel (8 mm tape), 10 k/box GS08/3 k per 7" reel (8 mm tape), 15 k/box

Part	Ordering code	Type Marking	Remarks
SD101AW-V	SD101AW-V-GS18 or SD101AW-V-GS08	SA	Tape and Reel
SD101BW-V	SD101BW-V-GS18 or SD101BW-V-GS08	SB	Tape and Reel
SD101CW-V	SD101CW-V-GS18 or SD101CW-V-GS08	SC	Tape and Reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Value	Unit
Peak reverse voltage		SD101AW-V	V _{RRM}	60	V
		SD101BW-V	V _{RRM}	50	V
		SD101CW-V	V _{RRM}	40	V
Power dissipation (Infinite heatsink)			P _{tot}	400 ¹⁾	mW
Forward continuous current			١ _F	30	mA
Maximum single cycle surge	10 µs square wave		I _{FSM}	2	A

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Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Thermal resistance junction to ambient air		R _{thJA}	300 ¹⁾	K/W	
Junction temperature		Tj	125 ¹⁾	°C	
Storage temperature range		T _{stg}	- 65 to + 150	°C	

¹⁾ Valid provided that electrodes are kept at ambient temperature

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Reverse breakdown voltage	I _R = 10 μA	SD101AW-V	V _(BR)	60			V
		SD101BW-V	V _(BR)	50			V
		SD101CW-V	V _(BR)	40			V
Leakage current	V _R = 50 V	SD101AW-V	I _R			200	nA
	V _R = 40 V	SD101BW-V	I _R			200	nA
	V _R = 30 V	SD101CW-V	I _R			200	nA
Forward voltage drop	I _F = 1 mA	SD101AW-V	V _F			410	mV
		SD101BW-V	V _F			400	mV
		SD101CW-V	V _F			390	mV
	I _F = 15 mA	SD101AW-V	V _F			1000	mV
		SD101BW-V	V _F			950	mV
		SD101CW-V	V _F			900	mV
Diode capacitance	V _R = 0 V, f = 1 MHz	SD101AW-V	CD			2	pF
		SD101BW-V	CD			2.1	pF
		SD101CW-V	CD			2.2	pF
Reverse recovery time	$I_F = I_R = 5 \text{ mA}$, recover to 0.1 I_R		t _{rr}			1	ns

Typical Characteristics

 $T_{amb} = 25$ °C, unless otherwise specified

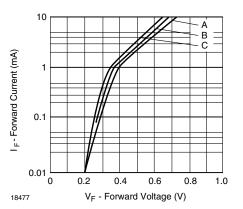


Figure 1. Typical Variation of Forward Current vs. Forward Voltage

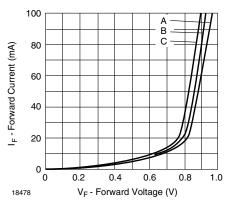


Figure 2. Typical Forward Conduction Curve



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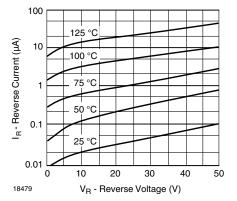


Figure 3. Typical Variation of Reverse Current at Various Temperatures

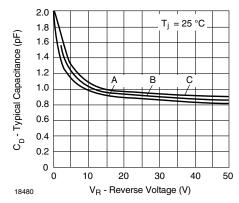
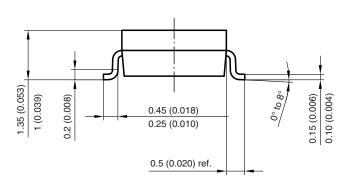
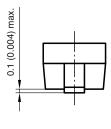


Figure 4. Typical Capacitance Curve as a Function of Reverse Voltage

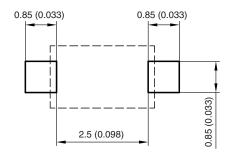






Cathode bar 2.85 (0.112) 2.55 (0.100) (90

Mounting Pad Layout



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